

Matched N-Channel JFET Pairs

Product Summary

Part Number	$V_{GS(off)}$ (V)	$V_{(BR)GSS}$ Min (V)	g_{fs} Min (mS)	I_G Typ (pA)	$ V_{GS1} - V_{GS2} $ Typ (mV)
U440	-1 to -6	-25	4.5	-1	10
U441	-1 to -6	-25	4.5	-1	20

Features

- Two-Chip Design
- High Slew Rate
- Low Offset/Drift Voltage
- Low Gate Leakage: 1 pA
- Low Noise
- High CMRR: 85 dB.

Benefits

- Minimum Parasitics Ensuring Maximum High-Frequency Performance
- Improved Op Amp Speed, Settling Time Accuracy
- Minimum Input Error/Trimming Requirement
- Insignificant Signal Loss/Error Voltage
- High System Sensitivity
- Minimum Error with Large Input Signal

Applications

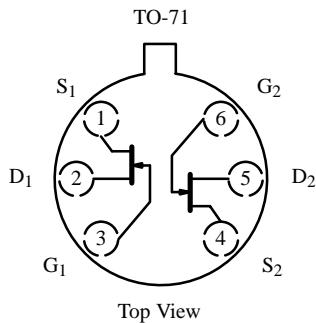
- Wideband Differential Amps
- High-Speed, Temp-Compensated, Single-Ended Input Amps
- High-Speed Comparators
- Impedance Converters

Description

The U440/441 are matched pairs of JFETs mounted in a single TO-71 package. This two-chip design reduces parasitics and gives better performance at very high frequencies while ensuring extremely tight matching. These devices are an excellent choice for use as wideband differential amplifiers in demanding test and measurement applications.

The hermetically-sealed TO-71 package is available with full military screening per MIL-S-19500 (see Military Information).

For similar products in SO-8 packaging see the SST440/SST441 data sheet. For low-noise options, see the SST/U401 series data sheet. For low-leakage alternatives, see the U421/423 data sheet.



Top View

Absolute Maximum Ratings

Gate-Drain, Gate-Source Voltage	-25 V	Operating Junction Temperature	-55 to 150°C
Gate-Gate Voltage	± 50 V	Power Dissipation : Per Side ^a	250 mW
Gate Current	50 mA	Total ^b	500 mW
Lead Temperature ($1/16$ " from case for 10 sec.)	300°C	Notes	
Storage Temperature	-65 to 200°C	a.	Derate 2 mW/°C above 25°C
		b.	Derate 4 mW/°C above 25°C

Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70251.

U440/441

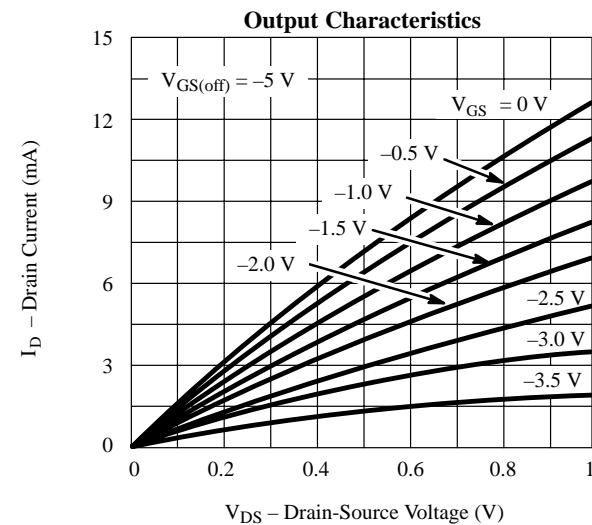
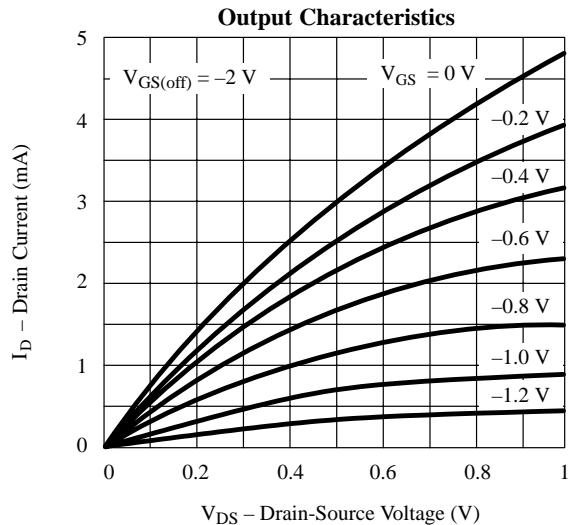
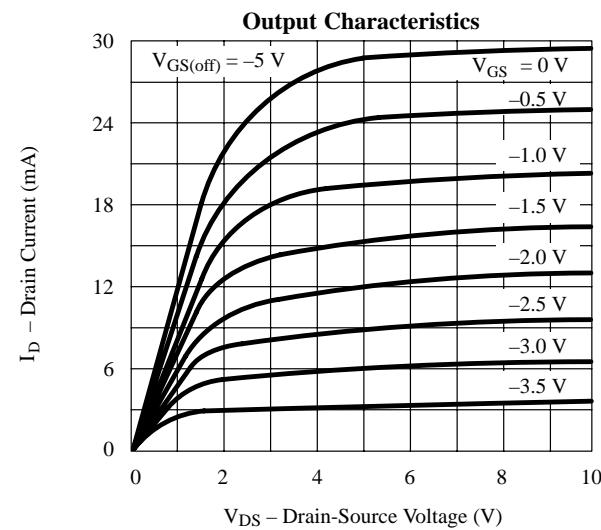
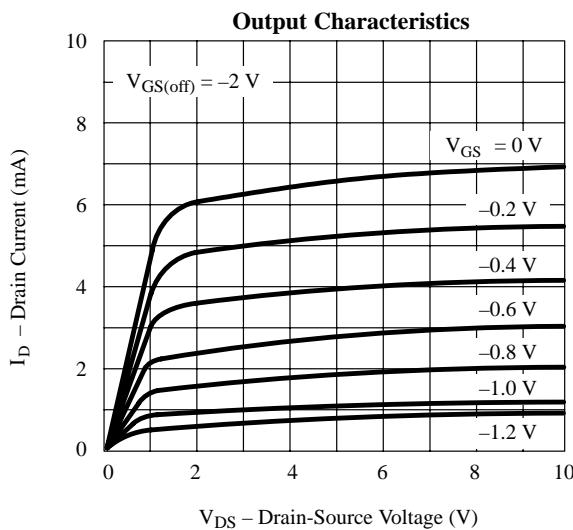
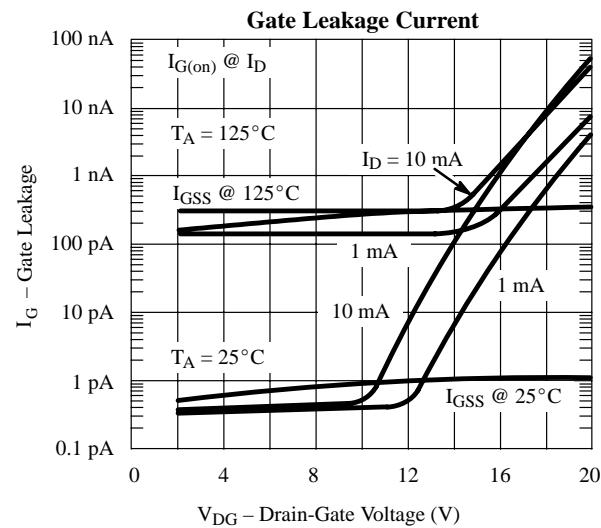
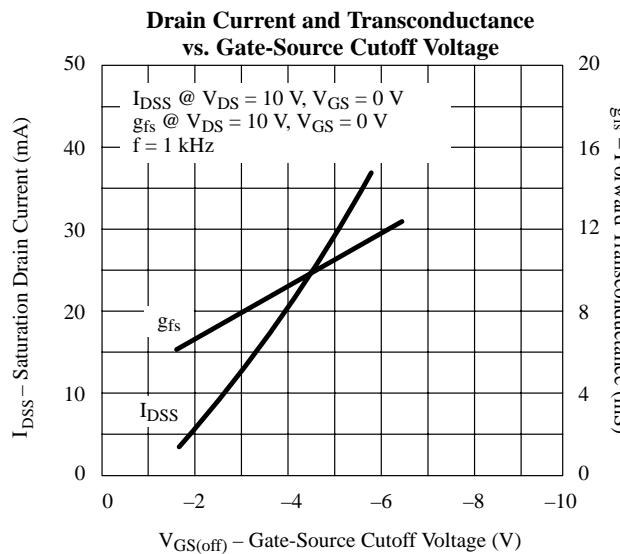
Specifications^a

Parameter	Symbol	Test Conditions	Typ ^b	Limits				Unit	
				U440		U441			
				Min	Max	Min	Max		
Static									
Gate-Source Breakdown Voltage	V _{(BR)GSS}	I _G = -1 μA, V _{DS} = 0 V	-35	-25		-25		V	
Gate-Source Cutoff Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 nA	-3.5	-1	-6	-1	-6		
Saturation Drain Current ^c	I _{DSS}	V _{DS} = 10 V, V _{GS} = 0 V	15	6	30	6	30	mA	
Gate Reverse Current	I _{GSS}	V _{GS} = -15 V, V _{DS} = 0 V T _A = 125°C	-1 -2		-500		-500	pA nA	
Gate Operating Current	I _G	V _{DG} = 10 V, I _D = 5 mA T _A = 125°C	-1 -0.3		-500		-500	pA nA	
Gate-Source Forward Voltage	V _{GS(F)}	I _G = 1 mA, V _{DS} = 0 V	0.7					V	
Dynamic									
Common-Source Forward Transconductance	g _{fs}	V _{DS} = 10 V, I _D = 5 mA f = 1 kHz	6	4.5	9	4.5	9	mS	
Common-Source Output Conductance	g _{os}		70		200		200	μS	
Common-Source Input Capacitance	C _{iss}	V _{DS} = 10 V, I _D = 5 mA f = 1 MHz	3					pF	
Common-Source Reverse Transfer Capacitance	C _{rss}		1						
Equivalent Input Noise Voltage	̄e _n	V _{DS} = 10 V, I _D = 5 mA f = 10 kHz	4					nV/ √Hz	
Matching									
Differential Gate-Source Voltage	V _{GS1} - V _{GS2}	V _{DG} = 10 V, I _D = 5 mA	6		10		20	mV	
Gate-Source Voltage Differential Change with Temperature	$\frac{\Delta V_{GS1} - V_{GS2} }{\Delta T}$	V _{DG} = 10 V, I _D = 5 mA T _A = -55 to 125°C	20					μV/°C	
Saturation Drain Current Ratio ^d	$\frac{I_{DSS1}}{I_{DSS2}}$	V _{DS} = 10 V, V _{GS} = 0 V	0.97						
Transconductance Ratio ^d	$\frac{g_{fs1}}{g_{fs2}}$	V _{DS} = 10 V, I _D = 5 mA f = 1 kHz	0.97						
Common Mode Rejection Ratio	CMRR	V _{DG} = 5 to 10 V, I _D = 5 mA	85					dB	

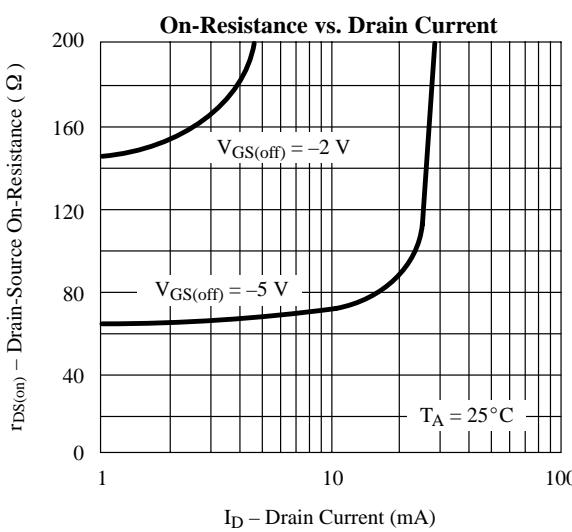
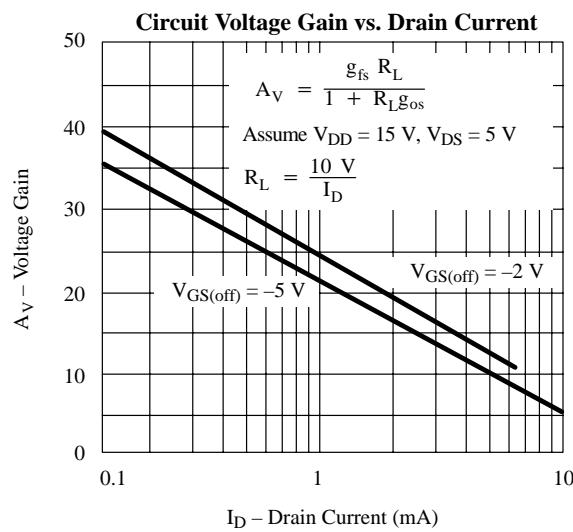
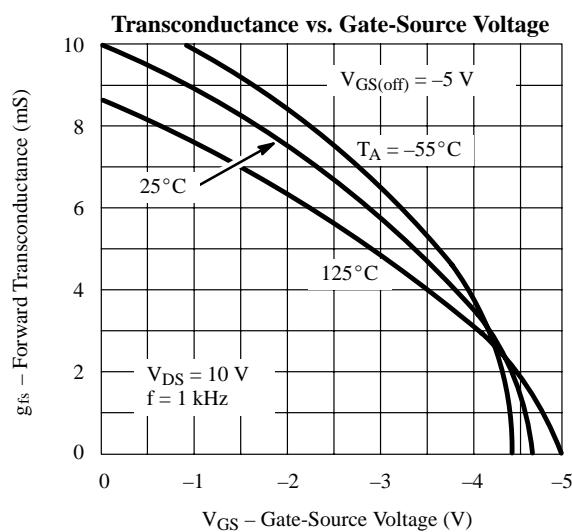
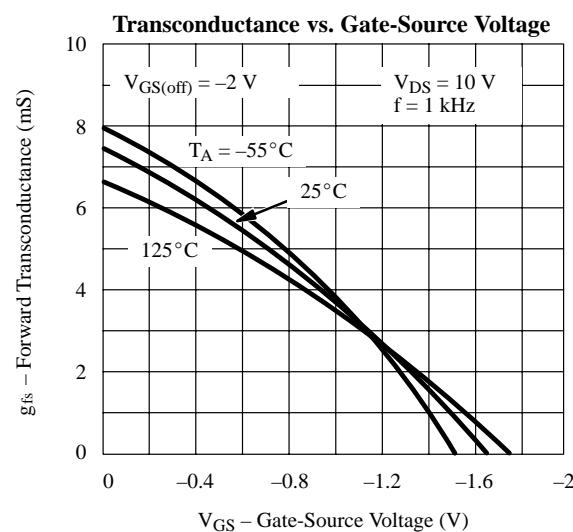
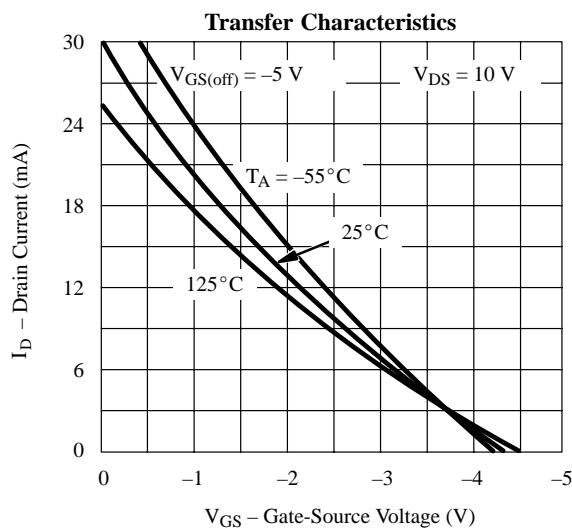
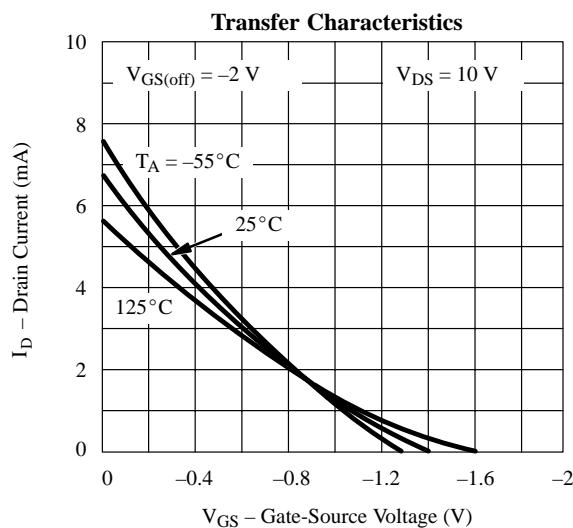
Notes

- a. T_A = 25°C unless otherwise noted.
- b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- c. Pulse test: PW ≤ 300 μs duty cycle ≤ 3%.
- d. Assumes smaller value in the numerator.

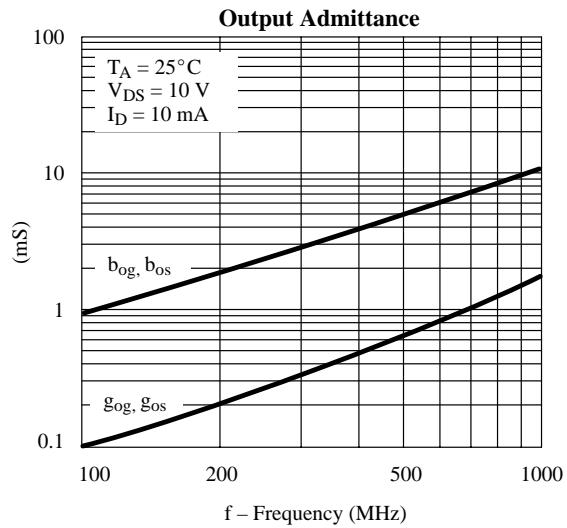
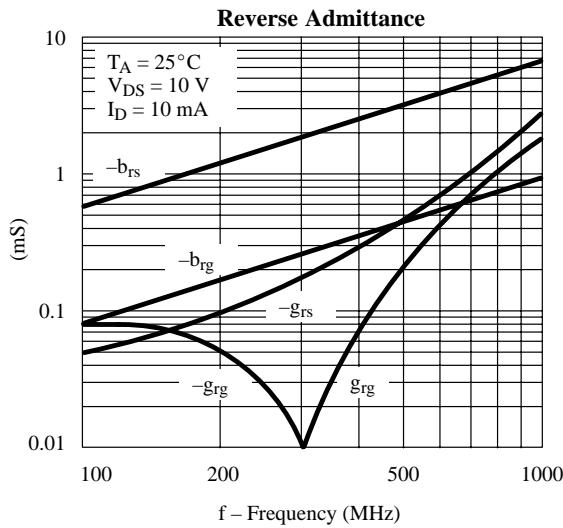
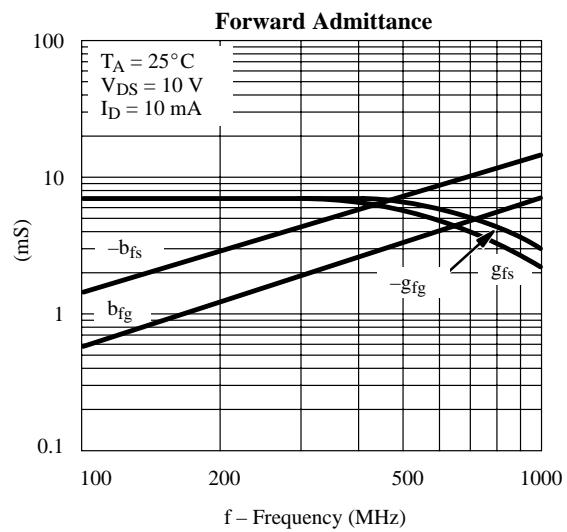
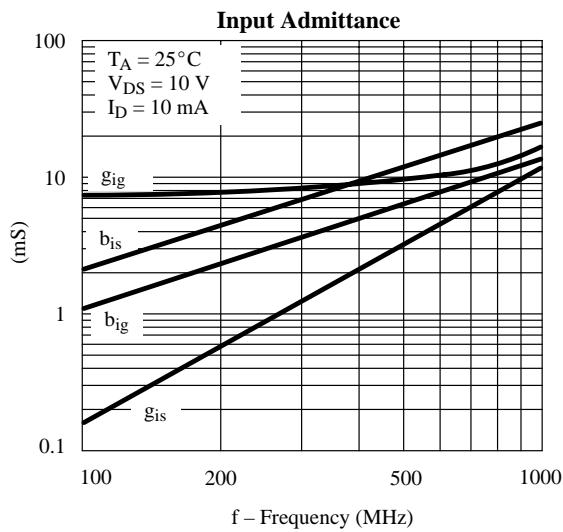
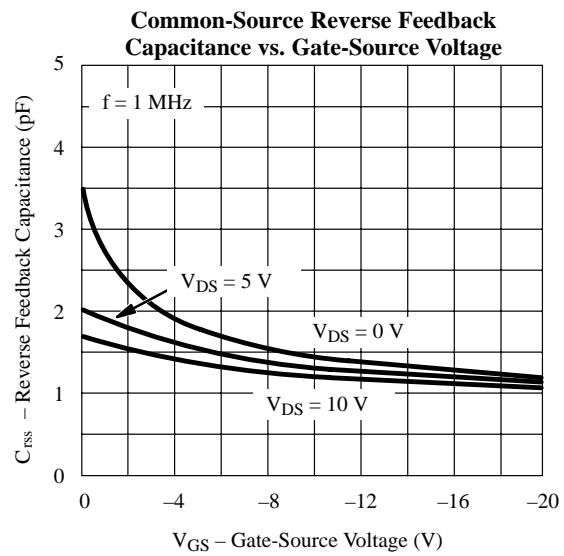
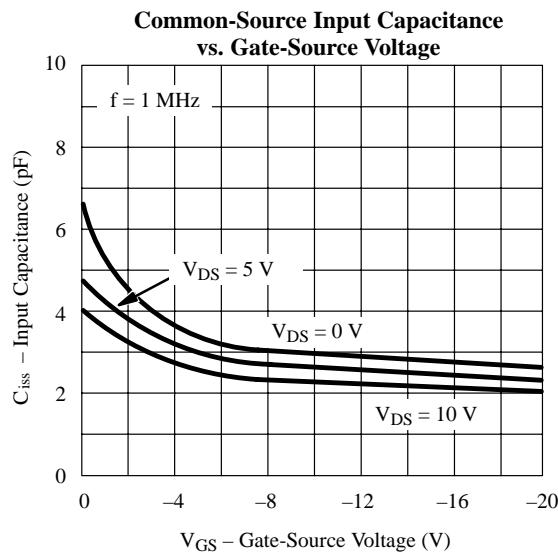
Typical Characteristics



Typical Characteristics (Cont'd)



Typical Characteristics (Cont'd)



Typical Characteristics (Cont'd)

